NSN 5961-01-338-3223

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Internal Configuration:
Junction contact
Mounting Method:
Terminal
Semiconductor Material:
Gallium arsenide phosphide
Voltage Rating In Volts Per Characteristic:
6.3 forward voltage, dc
Current Rating Per Characteristic:
150.00 milliamperes forward current, average absolute
Special Features:
Junction pattern arrangement: pn
Shelf Life:
N/a
Unit Of Measure:
Demilitarization:
Yes - demil/mli
Filg:
A110a0